

64K (8K x 8) CMOS EPROM

FEATURES

- · High speed performance
 - 120 ns access time available
- · CMOS Technology for low power consumption
 - 20 mA Active current
 - 100 μA Standby current
- · Factory programming available
- · Auto-insertion-compatible plastic packages
- · Auto ID aids automated programming
- · Separate chip enable and output enable controls
- High speed "express" programming algorithm
- · Organized 8K x 8: JEDEC standard pinouts
 - 28-pin Dual-in-line package
 - 32-pin Chip carrier (leadless or plastic)
 - 28-pin SOIC package
 - 28-pin TSOP package
 - Tape and reel
- · Available for the following temperature ranges:
 - Commercial:

0°C to +70°C

- Industrial:

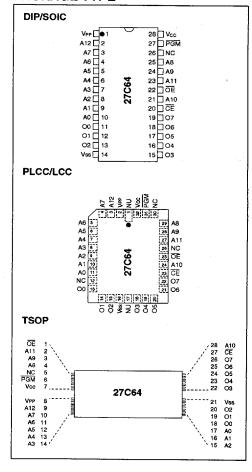
-40°C to +85°C

DESCRIPTION

The Microchip Technology Inc. 27C64 is a CMOS 64K bit (electrically) Programmable Read Only Memory. The device is organized as 8K words by 8 bits (8K bytes). Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 120 ns. CMOS design and processing enables this part to be used in systems where reduced power consumption and high reliability are requirements.

A complete family of packages is offered to provide the most flexibility in applications. For surface mount applications, PLCC, SOIC, or TSOP packaging is available. Tape and reel packaging is also available for PLCC or SOIC packages. UV erasable versions are also available.

PACKAGE TYPE



1.0 ELECTRICAL CHARACTERISTICS

1.1 Maximum Ratings*

Vcc and input voltages w.r.t. Vss......-0.6V to + 7.25V

VPP voltage w.r.t. Vss during
programming-0.6V to +14V

Voltage on A9 w.r.t. Vss-0.6V to +13.5V

Output voltage w.r.t. Vss-0.6V to Vcc +1.0V

Storage temperature-65°C to +150°C

Ambient temp. with power applied-65°C to +125°C

"Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: PIN FUNCTION TABLE

Name	Function
A0-A12	Address Inputs
CE	Chip Enable
OE .	Output Enable
PGM	Program Enable
VPP	Programming Voltage
00 - 07	Data Output
Vcc	+5V Power Supply
Vss	Ground
NC	No Connection; No Internal Connections
NU	Not Used; No External Connection Is Allowed

TABLE 1-2: READ OPERATION DC CHARACTERISTICS

Vcc = +5V (±10%) Commercial: Tamb = 0°C to +70°C Industrial: Tamb = -40°C to +85°C										
Parameter	Part*	Status	Symbol	Min	Max	Units	Conditions			
Input Voltages	all	Logic "1" Logic "0"	VIH VIL	2.0 -0.5	Vcc+1 0.8	V V				
Input Leakage	all	_	ÌLI	-10	10	μΑ	Vin = 0 to VCC			
Output Voltages	all	Logic "1" Logic "0"	Voh Vol	2.4	0.45	V	IOH = -400 μA IOL = 2,1 mA			
Output Leakage	all	_	ILO	-10	10	μΑ	VOUT = 0V to VCC			
Input Capacitance	all	_	CIN	_	6	рF	VIN = 0V; Tamb = 25°C; f = 1 MHz			
Output Capacitance	all		Соит	_	12	рF	Vout = 0V; Tamb = 25°C; f = 1 MHz			
Power Supply Current, Active	C	TTL input TTL input	ICC1 ICC2	_	20 25	mA mA	VCC = 5.5V; VPP = VCC; f = 1 MHz; OE = CE = VIL; lout = 0 mA; VIL = -0.1 to 0.8V; VIH = 2.0 to VCC; Note 1			
Power Supply Current, Standby	C I all	TTL input TTL input CMOS input	Icc(s)	_	2 3 100	mA mA μA	CE = Vcc ± 0.2V			
IPP Read Current VPP Read Voltage	all all	Read Mode Read Mode	IPP VPP	Vcc-0.7	100 Vcc	μA V	VPP = 5.5V Note 2			

^{*} Parts: C=Commercial Temperature Range; I =Industrial Temperature Range

Note 1: Typical active current increases .5 mA per MHz up to operating frequency for all temperature ranges.

Note 2: Vcc must be applied before VPP, and be removed simultaneously or after VPP.

TABLE 1-3: READ OPERATION AC CHARACTERISTICS

AC Testing Waveform: VIH = 2.4V and VIL = 0.45V; VOH = 2.0V VOL = 0.8V

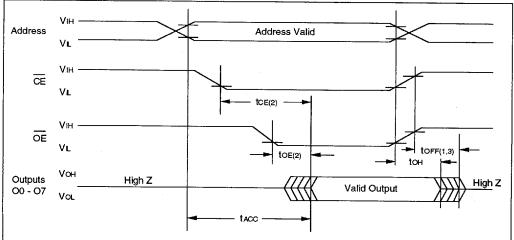
Output Load: 1 TTL Load + 100 pF Input Rise and Fall Times: 10 ns

Input Rise and Fall Times: 10 ns

Ambient Temperature: Commercial: Tamb = 0°C to +70°C

	Industrial:										Tamb = -40°C to +85°C				
Parameter	C	27C64-12		27C64-15		27C64-17		27C64-20		27C64-25					
raiametei	Sym	Min	Max	Min	Max	Min	Max	Min	Мах	Min	Max	Units	Conditions		
Address to Output Delay	tacc	_	120	_	150	-	170		200	_	250	ns	CE = OE = VIL		
CE to Output Delay	tCE	_	120		150		170		200	_	250	ns	ŌË = VIL		
OE to Output Delay	toe	_	65	_	70	_	70	_	75	_	100	ns	CE = VIL		
CE or OE to O/P High Impedance	toff	0	50	0	50	0	50	0	55	0	60	ns			
Output Hold from Address CE or OE, whichever occurs first	tон	0	_	0	_	0		0	_	0	-	ns			

FIGURE 1-1: READ WAVEFORMS



Note 1: tOFF is specified for \overline{OE} or \overline{CE} , whichever occurs first.

Note 2: $\overline{\text{OE}}$ may be delayed up to tCE - tOE after the falling edge of $\overline{\text{CE}}$ without impact on tCE.

Note 3: This parameter is sampled and is not 100% tested.

TABLE 1-4: PROGRAMMING DC CHARACTERISTICS

						Famb = 25°C ± 5°C P = VH = 13.0V ± 0.25V
Parameter	Status	Symbol	Min	Max.	Units	Conditions
Input Voltages	Logic"1" Logic"0"	VIH VIL	2.0 -0.1	Vcc+1 0.8	V V	
Input Leakage	_	iu	-10	10	μA	VIN = 0V to VCC
Output Voltages	Logic"1" Logic"0"	Voh Vol	2.4	 0.45	V	IOH = -400 μA IOL = 2.1 mA
Vcc Current, program & verify	_	ICC2	_	20	mA	Note 1
VPP Current, program	-	IPP2		25	mA	Note 1
A9 Product Identification		Vн	11.5	12.5	٧	

Note 1: Vcc must be applied simultaneously or before VPP and removed simultaneously or after VPP.

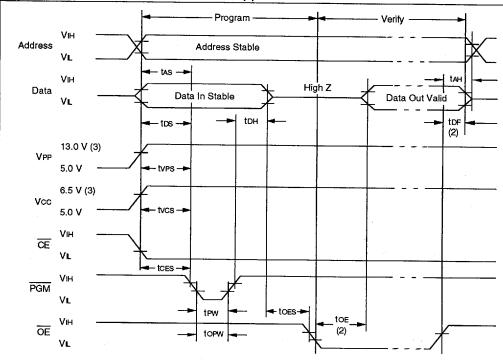
TABLE 1-5: PROGRAMMING AC CHARACTERISTICS

for Program, Program Verify and Program Inhibit Modes	Ambient Tempe	AC Testing Waveform: VIH=2.4V and VIL=0.45V; VOH=2.0V; VOL=0.8V Ambient Temperature: Tamb= 25° C $\pm 5^{\circ}$ C VCC= 6.5 V ± 0.25 V, VPP = VH = 13.0 V ± 0.25 V									
Parameter		Symbol	Min	Max	Units	Remarks					
Address Set-Up Time		tas	2		μs						
Data Set-Up Time		tos	2		μs						
Data Hold Time		tон	2		μs						
Address Hold Time		tan	0		μs						
Float Delay (2)		tDF	0	130	ns						
Vcc Set-Up Time		tvcs	2		μs	-					
Program Pulse Width (1)		tpw	95	105	μs	100 μs typical					
CE Set-Up Time		tces	2	_	μs						
OE Set-Up Time		toes	2	_	μs						
VPP Set-Up Time		tvps	2		μs						
Data Valid from OE		toE		100	ns						

Note 1: For express algorithm, initial programming width tolerance is 100 μs $\pm 5\%.$

Note 2: This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).

FIGURE 1-2: PROGRAMMING WAVEFORMS (1)



Notes: (1) The input timing reference is 0.8 V for V_{1L} and 2.0 V for V_{1H} .

(2) top and toe are characteristics of the device but must be accommodated by the programmer.

(3) $Vcc = 6.5 \text{ V} \pm 0.25 \text{ V}$, $VPP = VH = 13.0 \text{ V} \pm 0.25 \text{ V}$ for Express algorithm.

TABLE 1-6: MODES

Operation Mode	CE	ŌĒ	PGM	VPP	A9	00 - 07
Read	VIL	VIL	ViH	Vcc	X	Dout
Program	VIL	ViH	VIL	VH	Х	Din
Program Verify	Vı∟	VIL	ViH	Vн	х	Dout
Program Inhibit	ViH	x	X	VH	x	High Z
Standby	ViH	х	x	Vcc	x	High Z
Output Disable	VIL	ViH	ViH	Vcc	l x	High Z
Identity	VIL	VIL	ViH	Vcc	VH	Identity Code

X = Don't Care

1.2 Read Mode

(See Timing Diagrams and AC Characteristics)
Read Mode is accessed when

- a) the CE pin is low to power up (enable) the chip
- b) the $\overline{\text{OE}}$ pin is low to gate the data to the output pins

For Read operations, if the addresses are stable, the address access time (tACC) is equal to the delay from $\overline{\text{CE}}$ to output (tCE). Data is transferred to the output after a delay from the falling edge of $\overline{\text{OE}}$ (tOE).

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Standby Mode 1.3

The standby mode is defined when the CE pin is high (VIH) and a program mode is not defined.

When these conditions are met, the supply current will drop from 20 mA to 100 µA.

1.4 **Output Enable**

This feature eliminates bus contention in microprocessor-based systems in which multiple devices may drive the bus. The outputs go into a high impedance state when the following condition is true:

The OE and PGM pins are both high.

Erase Mode (U.V. Windowed 1.5 Versions)

Windowed products offer the capability to erase the memory array. The memory matrix is erased to the all 1's state when exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/cm2 is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of 12,000µW/cm2 for approximately 20 minutes.

1.6 **Programming Mode**

The Express Algorithm has been developed to improve the programming throughput times in a production environment. Up to ten 100-microsecond pulses are applied until the byte is verified. No overprogramming is required. A flowchart of the express algorithm is shown in Figure 1-3.

Programming takes place when:

- Vcc is brought to the proper voltage,
- VPP is brought to the proper VH level,
- the CE pin is low,
- the OE pin is high, and
- the PGM pin is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0-A12 and the data to be programmed is presented to pins O0-O7. When data and address are stable, \overline{OE} is high, \overline{CE} is low and a low-going pulse on the PGM line programs that location.

1.7 **Verify**

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- Vcc is at the proper level,
- b) VPP is at the proper VH level,
- the CE line is low,
- the PGM line is high, and d)
- the OE line is low.

1.8 <u>Inhibit</u>

When programming multiple devices in parallel with different data, only CE or PGM need be under separate control to each device. By pulsing the CE or PGM line low on a particular device in conjunction with the PGM or CE line low, that device will be programmed; all other devices with CE or PGM held high will not be programmed with the data, although address and data will be available on their input pins (i.e., when a high level is present on CE or PGM); and the device is inhibited from programming.

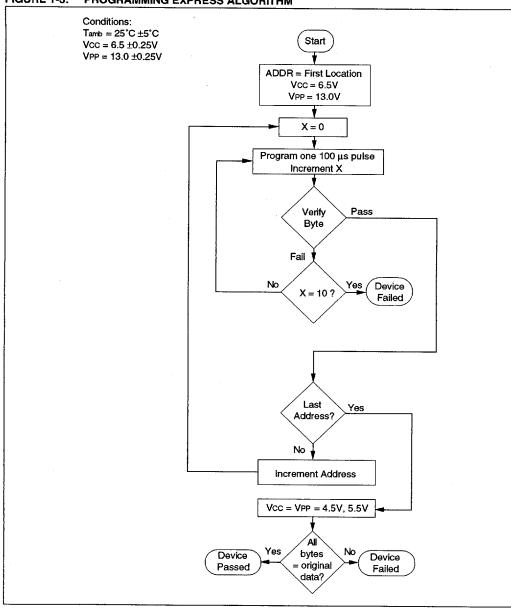
1.9 **Identity Mode**

In this mode, specific data is output which identifies the manufacturer as Microchip Technology Inc. and device type. This mode is entered when Pin A9 is taken to VH (11.5V to 12.5V). The $\overline{\text{CE}}$ and $\overline{\text{OE}}$ lines must be at VIL. A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin —	Input	Output								
Identity	AO	0 7	0	O 5	0	0	0	0	0	H e x
Manufacturer Device Type*	VIL VIH	0	0	1 0	0	1	0 0	0	1 0	29 02

^{*} Code subject to change

FIGURE 1-3: PROGRAMMING EXPRESS ALGORITHM



27C64 Product Identification System

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.

